

### **Product Overview**

The QPA9901 is a high-efficiency, linearizable power amplifier targeting Band 66 along with Band 1 small-cell wireless infrastructure systems. The product delivers high efficiency of 32% at +28dBm average output power, while providing excellent DPD linearized ACPR of -48dBc for signal bandwidths of up to 60MHz.

The QPA9901 is housed in a 5x5mm SMT package. It is pin-to-pin compatible to QPA9903 (band 3 high-efficiency small cell PA).

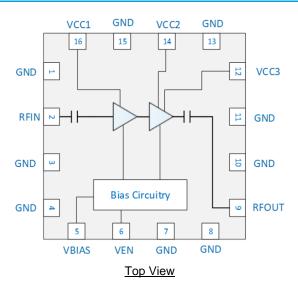


16 Pad 5 x 5 mm Package

# Key Features

- 2110-2200MHz
- Up to 60MHz IBW capability
- 36.5dB Gain typical
- 32% PAE at +28dBm power output
- <-48dBc ACPR DPD linearized at +28dBm Pout</li>
- 1.8V logic compatible PA ON/OFF control
- On chip ESD protection

# **Functional Block Diagram**



## **Applications**

- 3GPP Band 66 along with Band 1 Small Cells
- M-MIMO
- Repeaters / DAS
- Mobile Infrastructure
- General Purpose Wireless

## **Ordering Information**

Part No.	Description
QPA9901TR13	2500 on reel
QPA9901EVB-01	2110-2200 MHz EVB

# QPA9901 2110-2200MHz 4 W High-Efficiency Amplifier

## **Absolute Maximum Ratings**

Parameter	Rating
Storage Temperature	−55 to +125 °C
RF Input Power, Pulsed CW, 50 Ω (1)	+10 dBm
Device Voltage (Vcc)	+5.5 V

Exceeding any one or a combination of the Absolute Maximum Rac conditions may cause permanent damage to the device. Extendapplication of Absolute Maximum Rating conditions to the device may red device reliability.

#### Note:

## **Recommended Operating Conditions**

Parameter	Min	Тур	Max	Units
Device Voltage (Vcc)	+4.75	+5	+5.25	V
TCASE	-40		+85	°C
Tj for >10 <sup>6</sup> hours MTTF			+175	°C

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

## **Electrical Specifications**

Parameter	Conditions (1)	Min	Тур	Max	Units
Operational Frequency Range		2110		2200	MHz
Test Frequency			2140		MHz
Gain	Pout = +28 dBm	34	36.5		dB
Input Return Loss			-13		dB
Output P3dB	100 µs/1 ms, 10% duty cycle	35	+35.6		dBm
Power Added Efficiency (2)	Pout = +28 dBm	29	32		%
ACPR(Uncorrected) (2)	Pout = +28 dBm		-38	-34	dBc
ACPR(Uncorrected) (3)	Pout = +28 dBm		-33		dBc
ACPR(Corrected) (2)	Pout = +28 dBm		-48		dBc
Quiescent Current, Icq	Pins 12, 14 and 16		93		mA
Total Operating Current	Pins 5, 12, 14 and 16, Pout = +28 dBm		394		mA
Thermal Resistance, θ <sub>jc</sub>	Junction to case		24.7		°C/W
V <sub>EN</sub> High		1.17	1.8	Vcc	V
V <sub>EN</sub> Low		0	0	0.5	V
2nd Harmonic	Pout = +28 dBm		-45		dBc
3rd Harmonic	Pout = +28 dBm		-60		dBc

### Notes:

- 1. Test conditions unless otherwise noted: All  $V_{CC} \& V_{BIAS} = +5.0 \text{ V}, V_{EN} = +1.8 \text{ V}, \text{ Temp} = +25 ^{\circ}\text{C}, 50 \Omega \text{ system}.$
- 2. LTE, 20 MHz E-UTRA Test Model 1.1 or 3.1, PAR = 8.5 dB at 0.01% Probability
- 3. LTE, 20 MHz x 3 E-UTRA Test Model 1.1 or 3.1, PAR = 8.5 dB at 0.01% Probability

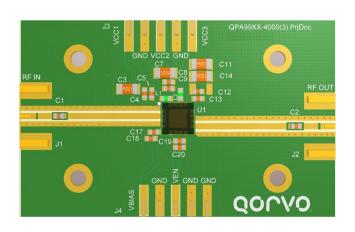
## **Power Amplifier Enable Logic Table**

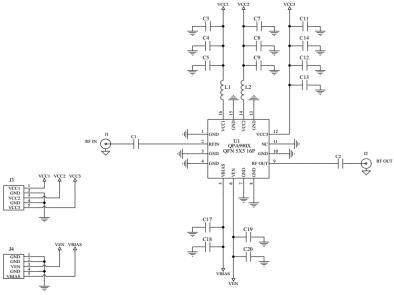
Parameter	High	Low
V <sub>EN</sub>	Power Amplifier ON	Power Amplifier OFF

<sup>1. 2110-2200</sup> MHz, Pulsed CW, 10% duty cycle, 100us period.



## 2110-2200 MHz Evaluation Board





#### Notes:

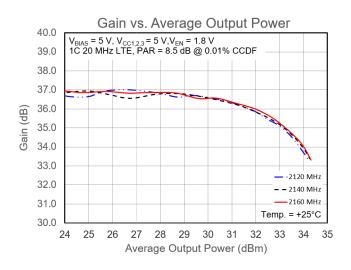
1. See Evaluation Board PCB Information for material and stack up.

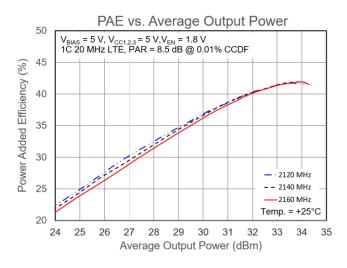
## Bill of Material - QPA9901EVB01

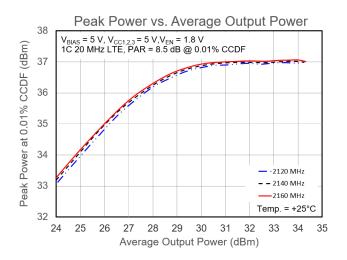
Reference Des.	Value	Description	Manuf.	Part Number
U1	-	Amplifier, QPA9901 2110-2200 MHz, High-Efficiency	Qorvo	QPA9901
C1, C2	100 pF	CAP,100 pF, 0603, 5%, 50V, NPO	various	
C5, C9, C13, C17, C19	1000 pF	CAP,1000 pF, 0603, 5%, 50V, NPO	various	
C4, C8, C12, C18, C20	0.1 μF	CAP,0.1 μF, 0603, 10%, 50V, X7R	various	
C3, C7, C14	10 μF	CAP, 10 μF, 1206, 16V	various	
L1, L2	0 Ω	RES 0 Ω, 0603, 1/16W, Chip	various	

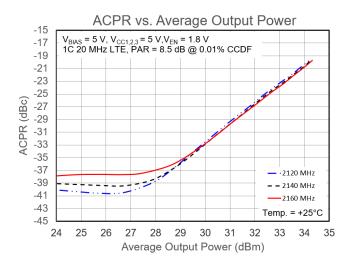


## Performance Plots - LTE, Over Frequency





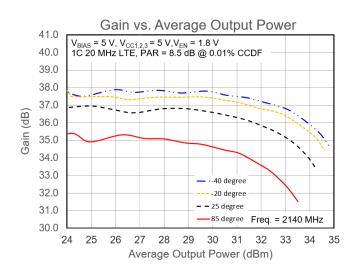


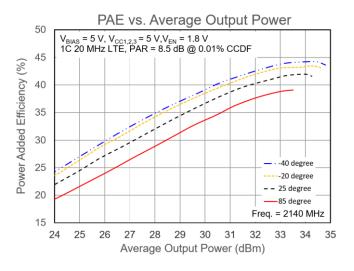


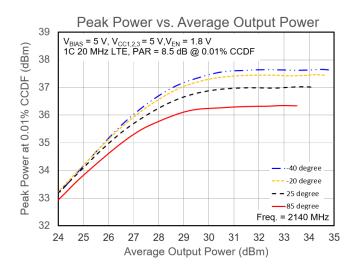
Test conditions unless otherwise noted: V<sub>BIAS</sub> = 5 V, V<sub>CC1,2,3</sub> = 5 V, V<sub>EN</sub> = 1.8 V, T = +25°C, tested using a single-carrier, 20 MHz LTE signal with 8.5 dB PAR at 0.01% CCDF on a reference design fixture.

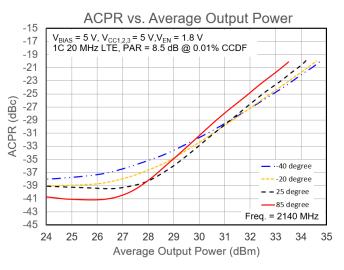


## Performance Plots - LTE, Over Temperature





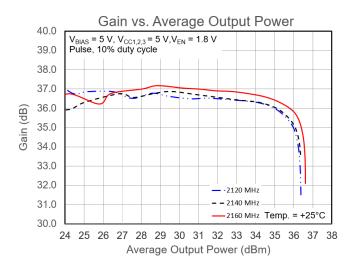


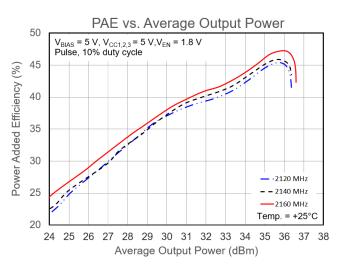


Test conditions unless otherwise noted: V<sub>BIAS</sub> = 5 V, V<sub>CC1,2,3</sub> = 5 V, V<sub>EN</sub> = 1.8 V, tested at 2140 MHz using a single-carrier, 20 MHz LTE signal with 8.5 dB PAR at 0.01% CCDF on a reference design fixture.

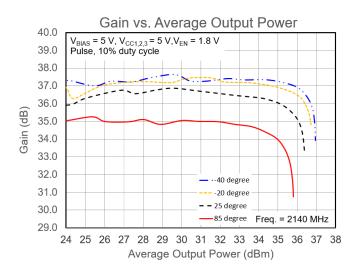


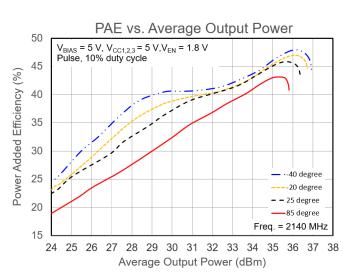
## Performance Plots - Pulse Signal Measurements, Frequency and Temperature





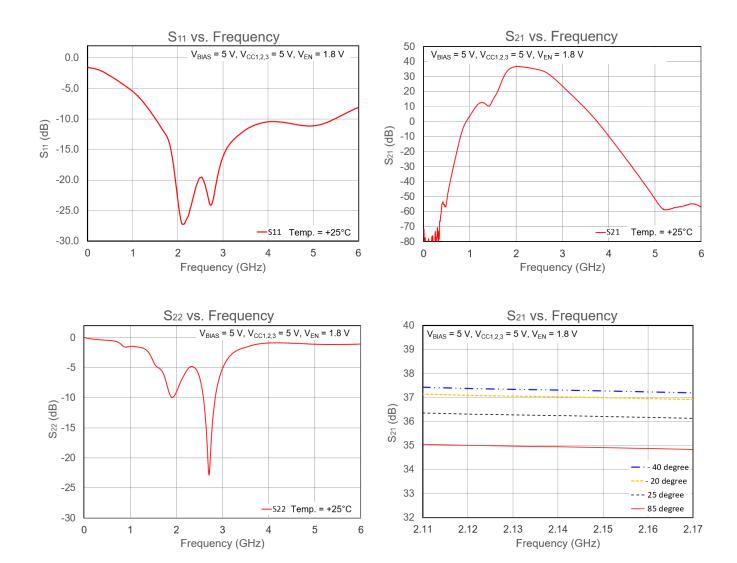
Test conditions unless otherwise noted: V<sub>BIAS</sub> = 5 V, V<sub>CC1,2,3</sub> = 5 V, V<sub>EN</sub> = 1.8 V, T = +25°C, tested using a pulse signal, 10% duty cycle.





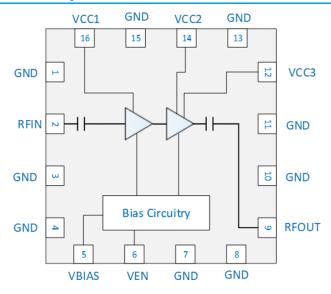
Test conditions unless otherwise noted: V<sub>BIAS</sub> = 5V, V<sub>CC1,2,3</sub> = 5V, V<sub>EN</sub> = 1.8 V, tested at 2140 MHz using a pulse signal, 10% duty cycle.

## Performance Plots - S-parameter



Test conditions unless otherwise noted:  $V_{BIAS} = 5 \text{ V}$ ,  $V_{CC1,2,3} = 5 \text{ V}$ ,  $V_{EN} = 1.8 \text{ V}$ .

# **Pad Configuration and Description**



Top View

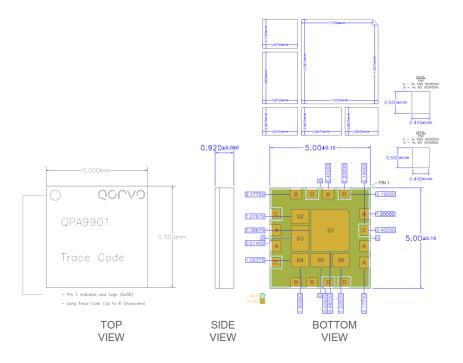
Pad No.	Label	Description	
1, 3, 4, 7, 8, 10, 11, 13, 15	GND	round connection.	
2	RF <sub>IN</sub>	RF input, internally matched to $50\Omega$ .	
5	V <sub>BIAS</sub>	Bias circuit supply voltage	
6	V <sub>EN</sub>	nplifier enable voltage (regulated internally)	
9	RFout	RF output, internally matched to $50\Omega$ . It has low impedance at DC. An external series capacitor is equired if high impedance is needed at DC.	
12	Vcc3	upply voltage for the various amplifier stages	
14	V <sub>CC2</sub>	Supply voltage for the various amplifier stages	
16	Vcc1	Driver stage supply voltage	
Backside Paddle	GND	Ground connection. The back side of the package should be connected to the ground plan though as short of a connection as possible. PCB via holes under the device are recommended.	





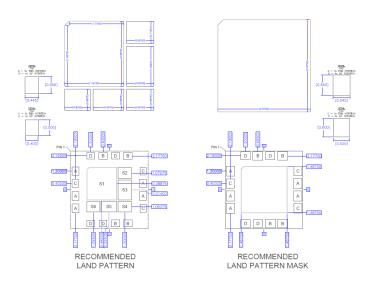
## **Package Marking and Dimensions**

Marking: Pin 1 Indicator and Qorvo Logo



- 1. All dimensions are in millimeters. Angles are in degrees.
- 2. The terminal #1 identifier and terminal numbering conform to JESD 95-1 SPP-012.
- 3. Contact plating: ENEPIG (Electroless Nickel Electroless Palladium Immersion Gold)

# **PCB Mounting Pattern**





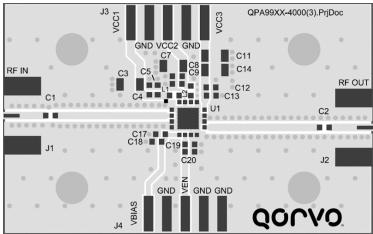
### **Evaluation Board PCB Information**

## **PC Board Layout**

### PCB Material (stackup)

Layer	Name	Material	Thickness	Constant
1	Top Overlay			
2	Top Solder	Solder Resist	0.40 mil	3.5
3	Top Layer	Copper	1.40 mil	
4	Dielectric1	RO4350	20.00 mil	3.48
5	Bottom Layer	Copper	1.40 mil	





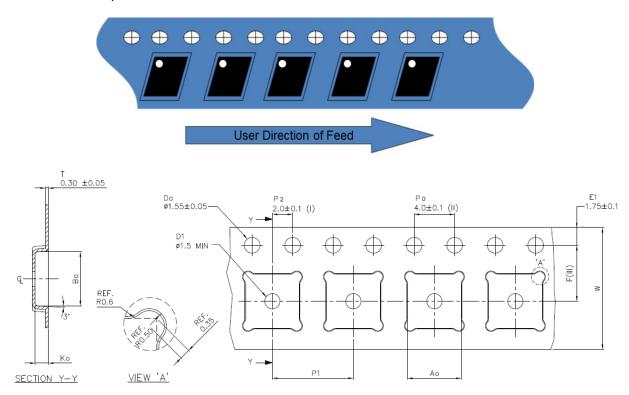
#### Notes

- 1. All dimensions are in millimeters. Angles are in degrees.
- 2. Use 1 oz. copper minimum for top and bottom layer metal.
- 3. Via holes are required under the backside paddle of this device for proper RF/DC grounding and thermal dissipation. We recommend a 0.35mm (#80/.0135") diameter bit for drilling via holes and a final plated thru diameter of 0.25 mm (0.10").
- 4. Ensure good package backside paddle solder attach for reliable operation and best electrical performance.



# **Tape and Reel Information – Carrier and Cover Tape Dimensions**

Tape and reel specifications for this part are also available on the Qorvo website. Standard T/R size = 2500 pieces on a 13" reel.

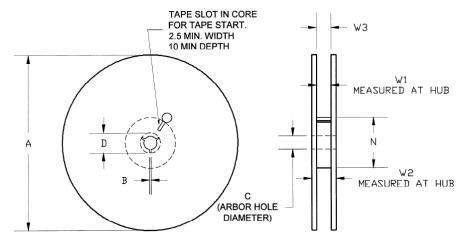


Feature	Measure	Symbol	Size (in)	Size (mm)
	Length	A0	0.209	5.3
Covity	Width	B0	0.209	5.3
Cavity	Depth	K0	0.051	1.3
	Pitch	P1	0.315	8.0
Centerline Distance	Cavity to Perforation - Length Direction	P2	0.079	2.0
Centenine Distance	Cavity to Perforation - Width Direction	F	0.217	5.5
Cover Tape	Width	С	0.362	9.2
Carrier Tape	Width	W	0.472	12



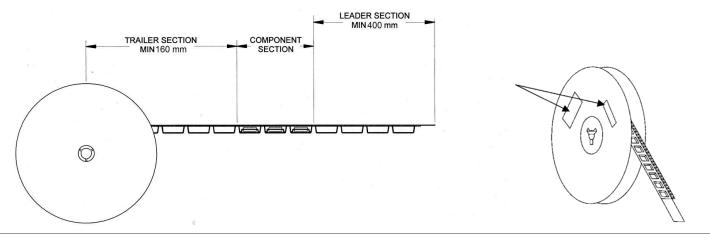
## **Tape and Reel Information – Reel Dimensions**

Packaging reels are used to prevent damage to devices during shipping and storage, loaded carrier tape is typically wound onto a plastic take-up reel. The reel size is 13" diameter. The reels are made from high-impact injection-molded polystyrene (HIPS), which offers mechanical and ESD protection to packaged devices.



Feature	Measure	Symbol	Size (in)	Size (mm)
	Diameter	Α	12.992	330.00
Flange	Thickness	W2	0.717	18.20
	Space Between Flange	W1	0.504	12.80
	Outer Diameter	N	4.016	102.00
Hub	Arbor Hole Diameter	С	0.512	13.00
nub	Key Slit Width	В	0.079	2.00
	Key Slit Diameter	D	0.795	20.2

# Tape and Reel Information - Tape Length and Label Placement

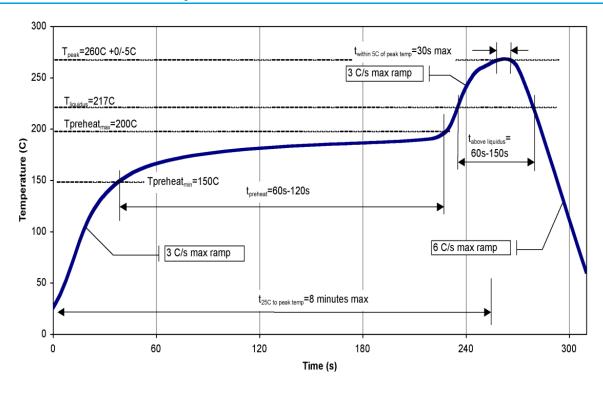


#### Notes:

- 1. Empty part cavities at the trailing and leading ends are sealed with cover tape. See EIA 481.
- 2. Labels are placed on the flange opposite the sprockets in the carrier tape.



# **Recommended Solder Temperature Profile**





# QPA9901 2110-2200MHz 4 W High-Efficiency Amplifier

## **Handling Precautions**

Parameter	Rating	Standard
ESD-Human Body Model (HBM)	1C	ESDA / JEDEC JS-001-2012
ESD-Charged Device Model (CDM)	C3	JEDEC JESD22-C101F
MSL-Moisture Sensitivity Level	3	IPC/JEDEC J-STD-020



Caution! ESD-Sensitive Device

## **Solderability**

Compatible with both lead-free (260°C max. reflow temp.) and tin/lead (245°C max. reflow temp.) soldering processes. Solder profiles available upon request.

Contact plating: ENEPIG (Electroless Nickel Electroless Palladium Immersion Gold)

## **RoHS Compliance**

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Product uses RoHS Exemption 7c-I to meet RoHS Compliance requirements.
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C15H12Br402) Free
- PFOS Free
- SVHC Free

### **Contact Information**

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: <u>www.qorvo.com</u> Tel: 1-844-890-8163

Email: <u>customer.support@qorvo.com</u>

For technical questions and application information:

Email: appsupport@gorvo.com

# **Important Notice**

The information contained herein is believed to be reliable; however, Qorvo makes no warranties regarding the information contained herein and assumes no responsibility or liability whatsoever for the use of the information contained herein. All information contained herein is subject to change without notice. Customers should obtain and verify the latest relevant information before placing orders for Qorvo products. The information contained herein or any use of such information does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other intellectual property rights, whether with regard to such information itself or anything described by such information. THIS INFORMATION DOES NOT CONSTITUTE A WARRANTY WITH RESPECT TO THE PRODUCTS DESCRIBED HEREIN, AND QORVO HEREBY DISCLAIMS ANY AND ALL WARRANTIES WITH RESPECT TO SUCH PRODUCTS WHETHER EXPRESS OR IMPLIED BY LAW, COURSE OF DEALING, COURSE OF PERFORMANCE, USAGE OF TRADE OR OTHERWISE, INCLUDING THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE.

Without limiting the generality of the foregoing, Qorvo products are not warranted or authorized for use as critical components in medical, life-saving, or life-sustaining applications, or other applications where a failure would reasonably be expected to cause severe personal injury or death.

Copyright 2021 © Qorvo, Inc. | Qorvo is a registered trademark of Qorvo, Inc.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Amplifier category:

Click to view products by Qorvo manufacturer:

Other Similar products are found below:

A82-1 BGA622H6820XTSA1 BGA 728L7 E6327 BGB719N7ESDE6327XTMA1 HMC397-SX HMC405 HMC561-SX HMC8120-SX HMC8121-SX HMC-ALH382-SX HMC-ALH476-SX SE2433T-R SMA3101-TL-E SMA39 A66-1 A66-3 A67-1 A81-2 LX5535LQ LX5540LL MAAM02350 HMC3653LP3BETR HMC549MS8GETR HMC-ALH435-SX SMA101 SMA32 SMA411 SMA531 SST12LP19E-QX6E WPM0510A HMC5929LS6TR HMC5879LS7TR HMC1087F10 HMC1086 HMC1016 SMA1212 MAX2689EWS+T MAAMSS0041TR MAAM37000-A1G LTC6430AIUF-15#PBF SMA70-2 SMA4011 A231 HMC-AUH232 LX5511LQ LX5511LQ-TR HMC7441-SX HMC-ALH310 XD1001-BD-000V A4011